

NCD is a next technology leader in the creation of **ALD** systems for **SOLAR** energy, **OLED**, and semiconductor.



R&D	R&D	R&D	Semiconductor	c-Si solar cell	CIGS solar cell	OLED
Lucida™ D ALD	Lucida™ M ALD	Lucida™ GS	Lucida™ MC ALD	Lucida™ GS ALD	Lucida™ TS ALD	Lucida™ GD ALD
< Ø200	< Ø200	156*156 mm	< Ø300	156*156 mm	< 900x1600 mm	< 1500x1850 mm

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NCD

Lucida™ M100 ALD

Plasma-enhanced atomic layer deposition system for R&D applications

Applications

- Thin film process for PEALD research
- Applications of R&D

Features

- PEALD thin films with good thickness uniformity and conformal step coverage
- Advanced process kit and minimize gas supply line length for short cycle times
- Direct plasma system
- Totally Integrated process module
- Easy process control
- Load-lock system

Technical specifications

Substrate size	150~300 mm
Substrate temperature	25°C~450°C(±0.2°C) @ 1Torr, in wafer
Precursor sources	3, heated 2 sources
Deposition uniformity	<±2%
Footprint	2600(L) x 650(W) x 1500(H) mm (include MTB)
Deposition mechanism	Dual shower-head type
Compatibility	Clean room class 100
Control system	PC control base (Full auto)
Optional	Up to 4 heated sources
Optional	Lucida cooler (2ch)



Lucida™ D100 ALD

Atomic layer deposition system for R&D applications

Applications

- Thin film process for ALD research : Al_2O_3 , ZnO , HfO_2 , ZrO_2 , TiO_2
- 100~200mm wafers

Benefits

- Applications of R&D.
- Very low price
- Various additional option

Features

- ALD ultra-thin films with good thickness uniformity and 100% conformal step coverage
- Advanced process kit and small-volume chamber for short cycle times
- Extremely materialize ALD Mechanism (Traveling wave method)
- Small foot print (950 x 700mm)
- Totally Integrated process module
- Easy process control
- Minimize gas supply line length

Technical specifications

Substrate size	100~200mm
Substrate temperature	25°C ~ 350°C ($\pm 0.2^\circ\text{C}$) @ 1Torr, in wafer
Precursor sources	3, heated 2 sources and H_2O source
Deposition uniformity	$< \pm 2\%$
Footprint	950 x 700 mm
Deposition mechanism	Traveling wave type
Compatibility	Clean room class 100
Control system	PC control base (Full auto)
Optional	Up to 4 heated sources
Optional	Lucida cooler(2ch)



Lucida™ GD series

High-throughput atomic layer deposition system for OLED displays

Features

- Al₂O₃ thin film encapsulation for OLED
- Al₂O₃ barrier layer for flexible substrates
- WVTR(water vapor transmission rate) of 5.3×10^{-6} g/m² day (@ 30nm Al₂O₃/PEN substrate)
- Applications of mass-production
- Industrial fully-automated production equipment
- High throughput : up to 30 panels/hour of 6G panels(1500x1850 mm²)

Specifications

Model	Material	Wafer size (mm ²)	Thickness (nm)	Throughput (panel/hour)
Lucida™ GD 200	Al ₂ O ₃	370x470	30	30
Lucida™ GD 400H	Al ₂ O ₃	460x730	30	30
Lucida™ GD 550Q	Al ₂ O ₃	650x750	30	30
Lucida™ GD 600	Al ₂ O ₃	1500x1850	30	30

※ We could be processed that substrate sizes of a variety



Process module for Lucida™ GD series



Cluster system for Lucida™ GD series

Lucida™ GS series

High-throughput atomic layer deposition system for surface passivation of c-Si solar cells

Features

- Al_2O_3 surface passivation of c-Si solar cells applications of mass-production
- Industrial fully-automated production equipment
- High throughput : up to 3200 wafers/hour of $156 \times 156 \text{mm}^2$
- Al_2O_3 thin films with good thickness uniformity
- Small foot print
- Totally integrated process module
- Easy process control
- Automatic cassette to cassette operation

Specifications

Model	Material	Wafer size (mm ²)	Thickness (nm)	Throughput (panel/hour)
Lucida™ GS 200	Al_2O_3	156x156	10	> 500
Lucida™ GS 800	Al_2O_3	156x156	10	> 1700
Lucida™ GS 1200	Al_2O_3	156x156	10	> 2400
Lucida™ GS 1600	Al_2O_3	156x156	10	> 3400



Lucida™ TS series

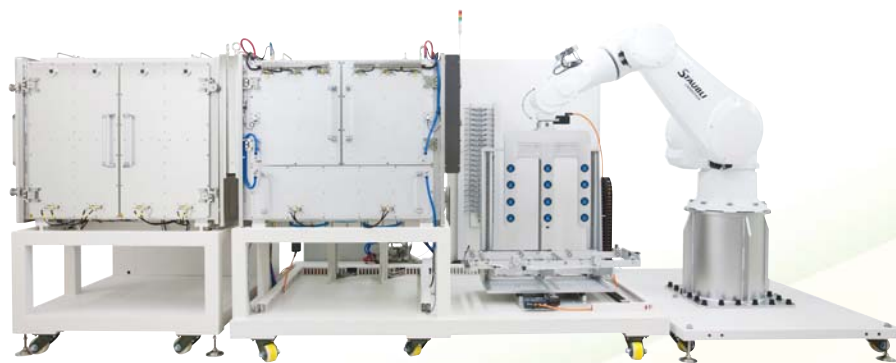
High-throughput atomic layer deposition system for buffer layer of CIGS solar cells

Features

- Zn(O,S) buffer layer of CIGS solar cells application of mass-production
- Industrial fully-automated production equipment
- High throughput up to 120 panels/hour of 900x1600mm²
- Zn(O,S) thin films with good thickness uniformity
- Small foot print
- Totally integrated process module
- Easy process control
- Automatic glass to glass operation

Specifications

Model	Material	Glass size (mm)	Thickness (nm)	Throughput (Panels/hr)
Lucida™ TS 1600	Zn(O,S)	900x1600	30	120 (40@1PM)
Lucida™ TS 1600-IN	Zn(O,S)	900x1600	30	120



Lucida™ TS1600 ALD system



Lucida™ TS1600-IN ALD system